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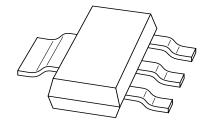
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Kind regards,

Team Nexperia

DISCRETE SEMICONDUCTORS

DATA SHEET



BAT160 seriesSchottky barrier double diodes

Product data sheet Supersedes data of 1999 Mar 26 1999 Sep 20



Schottky barrier double diodes

BAT160 series

FEATURES

- Low switching losses
- Capability of absorbing very high surge current
- · Fast recovery time
- · Guard ring protected
- Plastic SMD package.

APPLICATIONS

- Low power switched-mode power supplies
- Rectification
- · Polarity protection.

DESCRIPTION

Planar Schottky barrier double diodes encapsulated in a SOT223 plastic SMD package.

MARKING

| TYPE NUMBER | MARKING CODE |
|-------------|-----------------|
| BAT160A | AT160A |
| BAT160C | AT160C |
| BAT160S | AT160S |

PINNING

| PIN | BAT160 | | | | | | |
|------|---------------------------------|---------------------------------|---------------------------------|--|--|--|--|
| FIIN | Α | ၁ | 8 | | | | |
| 1 | k ₁ | a ₁ | a ₁ | | | | |
| 2 | n.c. | n.c. | n.c. | | | | |
| 3 | k ₂ | a ₂ | k ₂ | | | | |
| 4 | a ₁ , a ₂ | k ₁ , k ₂ | k ₁ , a ₂ | | | | |

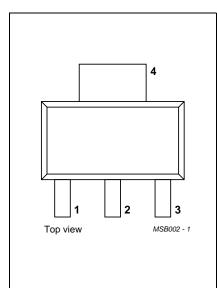


Fig.1 Simplified outline (SOT223) and pin configuration.

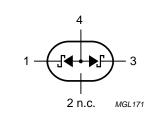
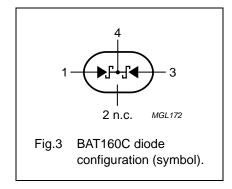


Fig.2 BAT160A diode configuration (symbol).



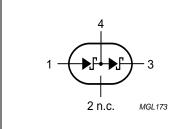


Fig.4 BAT160S diode configuration (symbol).

Schottky barrier double diodes

BAT160 series

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|------------------|-------------------------------------|---|------|------|------|
| Per diode | | | | | |
| V _R | continuous reverse voltage | | _ | 60 | V |
| I _F | continuous forward current | | _ | 1 | Α |
| I _{FSM} | non-repetitive peak forward current | t _p = 8.3 ms; half sinewave; JEDEC method | - | 10 | А |
| I _{RSM} | non-repetitive peak reverse current | t _p = 100 μs | _ | 0.5 | Α |
| T _{stg} | storage temperature | | -65 | +150 | °C |
| Tj | junction temperature | | _ | 150 | °C |

ELECTRICAL CHARACTERISTICS

T_{amb} = 25 °C unless otherwise specified.

| SYMBOL | PARAMETER | CONDITIONS | MAX. | UNIT | | | | |
|----------------|-------------------|---|------|------|--|--|--|--|
| Per diode | | | | | | | | |
| V _F | forward voltage | see Fig.5 | | | | | | |
| | | I _F = 100 mA | 400 | mV | | | | |
| | | I _F = 1 A | 650 | mV | | | | |
| | | I _F = 2 A | 850 | mV | | | | |
| I _R | reverse current | V _R = 60 V; note 1; see Fig.6 | 350 | μА | | | | |
| | | $V_R = 60 \text{ V}; T_j = 100 ^{\circ}\text{C}; \text{ note 1};$ see Fig.6 | 8 | mA | | | | |
| C _d | diode capacitance | $f = 1 \text{ MHz}$; $V_R = 4 \text{ V}$; see Fig 7 | 60 | pF | | | | |

Note

1. Pulse test: t_p = 300 μ s; δ = 0.02.

THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | CONDITIONS | VALUE | UNIT |
|---------------------|---|------------|-------|------|
| R _{th j-a} | thermal resistance from junction to ambient | note 1 | 100 | K/W |

Note

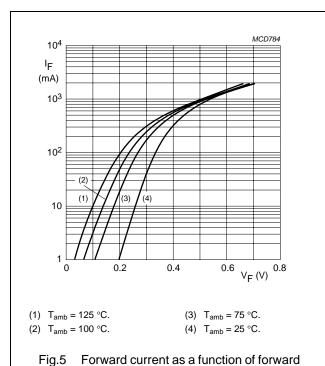
1. Refer to SOT223 standard mounting conditions.

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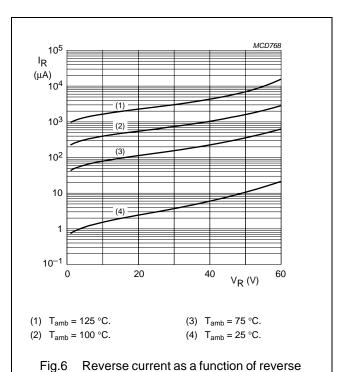
Schottky barrier double diodes

BAT160 series

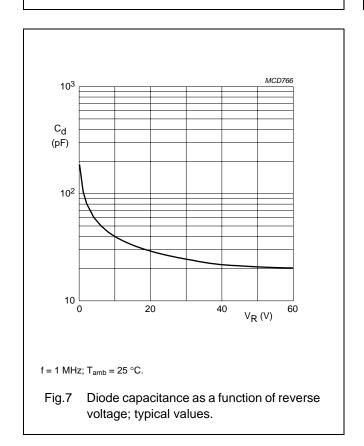
GRAPHICAL DATA



voltage; typical values.



voltage; typical values.



4

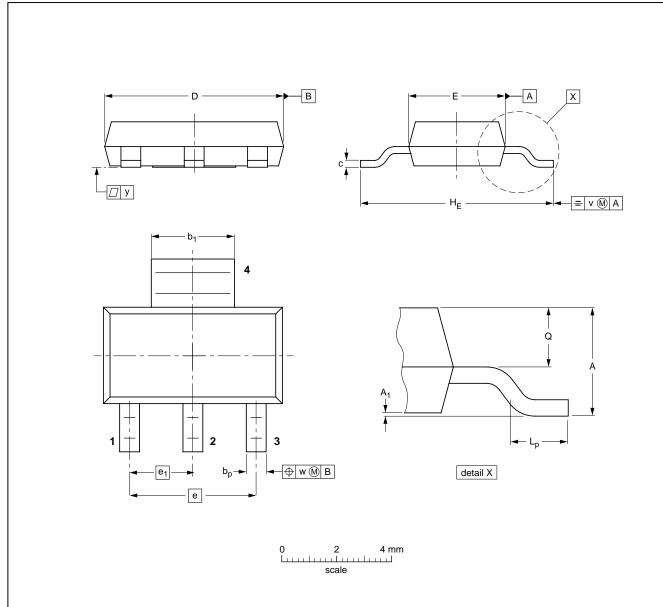
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BAT160 series

PACKAGE OUTLINE

Plastic surface mounted package; collector pad for good heat transfer; 4 leads

SOT223



DIMENSIONS (mm are the original dimensions)

| UNIT | A | A ₁ | bp | b ₁ | С | D | E | е | e ₁ | HE | Lp | Q | v | w | у |
|------|------------|----------------|--------------|----------------|--------------|------------|------------|-----|----------------|------------|------------|--------------|-----|-----|-----|
| mm | 1.8 1.5 | 0.10 0.01 | 0.80 0.60 | 3.1 2.9 | 0.32 0.22 | 6.7 6.3 | 3.7 3.3 | 4.6 | 2.3 | 7.3 6.7 | 1.1 0.7 | 0.95 0.85 | 0.2 | 0.1 | 0.1 |

| OUTLINE | | REFER | EUROPEAN | ISSUE DATE | | |
|---------|-----|-------|----------|------------|------------|----------------------------------|
| VERSION | IEC | JEDEC | EIAJ | | PROJECTION | ISSUE DATE |
| SOT223 | | | SC-73 | | | -97-02-28 99-09-13 |

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Schottky barrier double diodes

BAT160 series

DATA SHEET STATUS

| DOCUMENT STATUS ⁽¹⁾ | PRODUCT STATUS ⁽²⁾ | DEFINITION |
|-----------------------------------|----------------------------------|---|
| Objective data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary data sheet | Qualification | This document contains data from the preliminary specification. |
| Product data sheet | Production | This document contains the product specification. |

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NXP Semiconductors

Customer notification

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Contact information

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